

## Correlated noises for NUV-HD-Cryo SiPMs

#### Alessandro Razeto – LNGS

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## **Optical Cross-Talk**





- Biased silicon junctions emits light (Newman 1955)
- In SiPMs 1 photon every 106 e- (Mirzoyan 2009)
  - Emission is peaked at longer wavelengths
- Photon emission is the origin of cross-talk
  - Between SPADS or between SiPMs

# **Light Emission Microscopy**







PD18 – Workshop on PhotoDetectors *D. Strom - Max Planck Institute* https://l.infn.it/strom

# **Light Emission Microscopy**





Hamamatsu LCT4

Cell size =  $100 \times 100 \text{ um2}$ 

Breakdown voltage = 51.89V

CCD Channel [X]

## A different strategy





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## LAr chambers







## LAr chambers





- 5 x 5 x 5.1 cm<sup>3</sup> chamber
  - Lined with 3M reflective foil
  - Top & bottom window in fused silica
    - Collection efficiency ~ 85%
- Internal surfaces TPB evaporated
- Top & bottom 5x5 cm2 SiPM tiles
  - 88% SiPM coverage



## NUV-HD-Cryo



300



1e-03

100

200

T [K]

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## Internal cross-talk





## Internal cross-talk





# Light yield





## Asymmetric setup





# Is really eCT?







- The top and bottom windows are replaced <sup>ov [V]</sup> with optical filters
  - Optical cross-talk is peaked in RED & IR
- We get the flat line  $\rightarrow$  <u>eCT evidence</u>

Symmetric setup		D:		
		Bias	Asymmetric	
contribution	/	Algorithm tMC		С
eCT	$\neq$	$\bar{n}^{\mathrm{pe}}$	$13.0 \pm 0.5$	$12.1 \pm 0.3$
зе. fcт		C	$0.34 \pm 0.05$	$0.34 \pm 0.10$
	/	$\dot{V}_h$	5.4	5.4
S Primary	-/	$V_e$	$1.0 \pm 0.1$	$1.0 \pm 0.1$
₹ 28 ·	//	ξict	53	53
	-	ξfCT	$15 \pm 1$	15
5		$\xi_{eCT}$	$7 \pm 1$	$7 \pm 1$
10 -		α		
		$\delta^*$		
		$\chi^2/n.d.f.$	4 / 5	3 / 6
0 -			,	,
<sup>1</sup> <sup>2</sup> <sup>3</sup> <sup>4</sup> <sup>overvoltage</sup> [v] <sup>7</sup> It is possible to model the gross LY				
$P_{\text{PDE}}(V) = \zeta \cdot P_T^e(V - V_{bd}^A) + (1 - \zeta) \cdot P_T^h(V - V_{bd}^A)$	<ul> <li>Triggering probabilities for h<sup>+</sup> &amp; e<sup>-</sup></li> </ul>			
$\lambda_{\mathrm{xCT}}(V_S, V_T) = \xi_x \cdot (V_S - V_{bd}^C) \cdot P_T^h(V_T - V_{bd}^A)$	<ul> <li>Photon interaction probability</li> </ul>			
$IV_{\alpha}(V) = \frac{\bar{n}^{\mathrm{pe}} \cdot P_{\mathrm{PDE}}(V)}{-}$	Optica	al cross-tall	<	
$\frac{1}{1 - (\lambda_{iCT}(V) + \lambda_{fCT}(V) + \lambda_{eCT}(V))}$	Net as	symptotic L	V	14

Net asymptotic LY 

## Resolution





## On larger detectors?

- Simulated a TPC with ~2000 10x10 cm<sup>2</sup> SiPM tiles
- With an exposure of 200 t y
- Using a toy Monte Carlo that includes only the SiPM oCT models
  - Optics and disuniformities are not simulated
  - 3 10<sup>10</sup> e<sup>-</sup> events simulated











- 3 10<sup>10</sup> e<sup>-</sup> blue-gold
  - 10<sup>6</sup> n grey
    - Black = 50%
    - Green = 90%
  - Acceptance in red
    - 10 events

## Acceptance regions





- 10 e<sup>-</sup> in 3 10<sup>10</sup> events
  - Leakage 0.1 in 200 t y
    - 10 e- in the acceptance
  - Using Uar (1400 depletion)
  - Binomial energy estimators much better
    - ICT is not accounted

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# Projected sensitivity INFN

### • A note of caution

- Only oCT and AP are simulated
  - Real experiments would include more disuiniformities
- <u>The projected sensitivity is over-</u> estimated by a factor 2
- An opportune analysis algorithm can mitigate the iCT contribution
  - That is dominant
  - But eCT remains
  - And asymmetric events will be a problem

## Conclusions



- The eCT in SiPM is a real effect
  - With possible large effects on experiments
    - A case of a Ar-based experiment was shown
  - It is important to account eCT in reflective chambers
- Solutions are available to reduce it
  - Analysis
  - Fully opaque tranches
    - FBK achieved few % of iCT with metal filled tranches
  - Optical filters to absorb long wavelengths

## Backup



